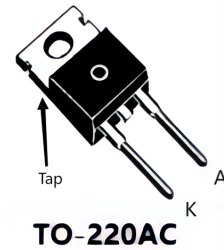


# ESTF15SS60SC

## Super Fast Recovery Diode

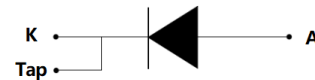
### Features

- Hyperfast Recovery  $t_{rr} = 40 \text{ ns}$  (@  $I_F = 15 \text{ A}$ )
- Max Forward Voltage,  $V_F = 2.1 \text{ V}$  (@  $T_C = 25^\circ\text{C}$ )
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- RoHS Compliant



### Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose



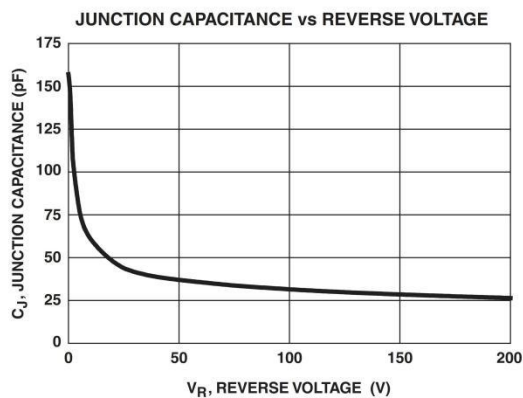
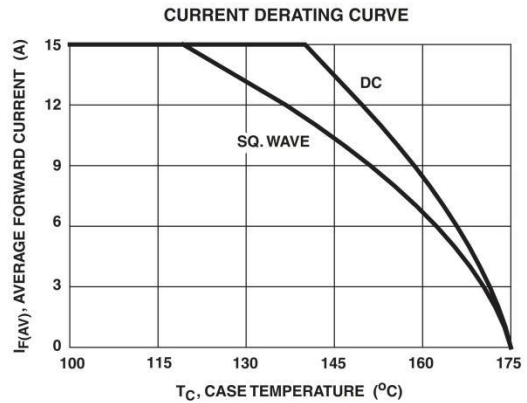
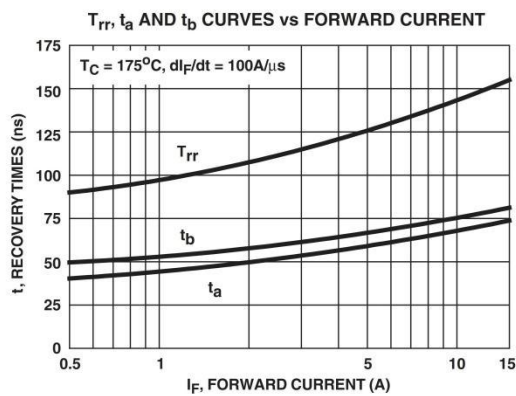
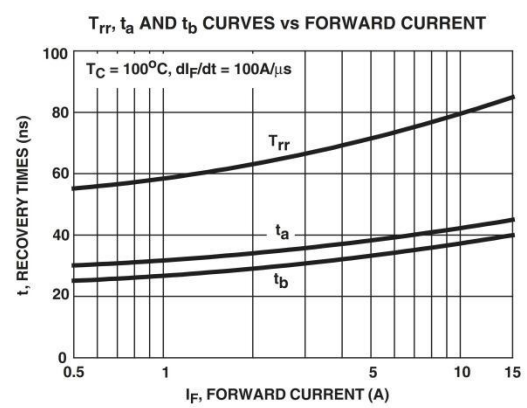
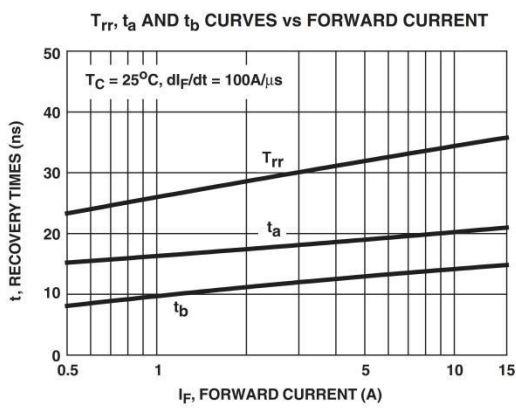
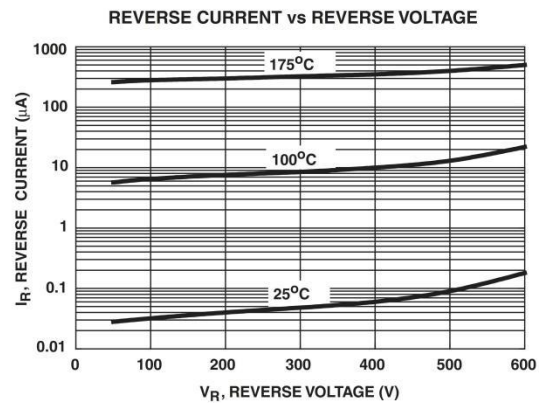
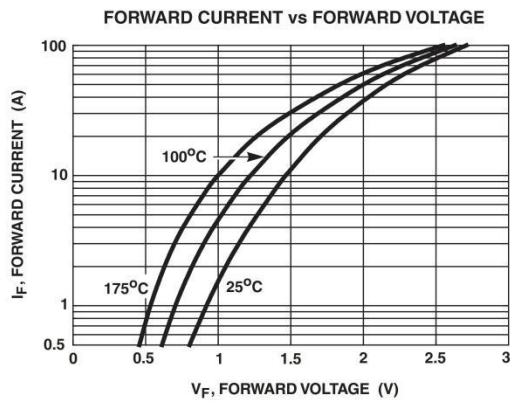
### Absolute Maximum Ratings @ $T_C=25^\circ\text{C}$

| Symbol      | Parameter                                         | ratings  | Unit             |
|-------------|---------------------------------------------------|----------|------------------|
| $V_{RRM}$   | Repetitive peak reverse voltage @50 $\mu\text{A}$ | 600      | V                |
| $V_{RWM}$   | Working Peak Reverse Voltage                      | 600      | V                |
| $I_{F(AV)}$ | Average forward current @ $T_C=110^\circ\text{C}$ | 15       | A                |
| $I_{FSM}$   | Peak one Cycle Surge Forward @ $t=8.3\text{ms}$   | 30       | A                |
| $E_{AVL}$   | Avalanche Energy(per diode) (1A, 40mH)            | 20       | mJ               |
| $T_j$       | Junction Temperature                              | -40~+150 | $^\circ\text{C}$ |
| $T_{STG}$   | Storage temperature range                         | -65~+175 | $^\circ\text{C}$ |

### Electrical Specifications @ $T_C=25^\circ\text{C}$

| Symbol               | Parameter                                                              |                                  | Ratings |     |     | Unit |
|----------------------|------------------------------------------------------------------------|----------------------------------|---------|-----|-----|------|
|                      |                                                                        |                                  | Min     | Typ | Max |      |
| I <sub>R</sub>       | T <sub>J</sub> =25℃                                                    | V <sub>R</sub> =V <sub>RRM</sub> |         |     | 100 | μA   |
|                      | T <sub>J</sub> =125℃                                                   |                                  |         |     | 500 | μA   |
| V <sub>F</sub>       | T <sub>J</sub> =25℃                                                    | I <sub>F</sub> =15A              |         |     | 2.1 | V    |
|                      | T <sub>J</sub> =125℃                                                   |                                  |         |     | 1.7 | V    |
| T <sub>rr</sub>      | I <sub>F</sub> =1A, I <sub>R</sub> =1A, I <sub>RR</sub> =0.25A         |                                  |         |     | 35  | ns   |
| T <sub>rr</sub>      | I <sub>F</sub> =15A, V <sub>R</sub> =30V, di <sub>F</sub> /dt=-100A/μs |                                  |         |     | 40  | ns   |
| Q <sub>rr</sub>      | I <sub>F</sub> =15A, di <sub>F</sub> /dt=-100A/μs                      |                                  |         |     | 40  | nC   |
| R <sub>th(j-c)</sub> | Thermal resistance from junction to case                               | TO-220AC                         |         | 1.5 |     | ℃/W  |

### Typical Performance Curves



### Package

